

Planar Superconducting Magnetic Flux Transformer with Micro- and Nanosized Branches

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The object of the study is a superconducting film magnetic flux transformer comprising two square shaped loops with the tapering active strips and a magnetosensitive film element between them. It is shown that splitting of the active strips into parallel micro- and nanosized superconducting branches and slits increases the gain factor of the transformer, i. e., the concentration of an external magnetic field on the magnetosensitive element, by a factor of more than six.

Keywords: Magnetic flux transformer, Superconducting film, Factor of multiplication (concentration), Micro- and nanosized branches and slits, Magnetosensitive element, Giant magnetoresistance, Magnetic field sensor.

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1. INTRODUCTION

Weak magnetic fields ($B \leq 10$ pT) are currently measured by different magnetometers [1-4]: SQUIDs (superconducting quantum interference devices), atomic, optical magnetometers, etc. The most sensitive of them are SQUIDs based on the effect of superconducting electrons tunneling through a weak link (Josephson junction or transition), but they do not measure the absolute value of a magnetic field and only detect changes in it. For SQUIDs, the magnetic field resolution δB , i.e., the minimum detectable magnetic field, is ~ 1 fT.

As the magnetosensitive element (MSE), any materials with sufficient nonlinearity of their magnetic characteristic can be used, for example, Hall sensors, materials and structures based on the effect of giant magnetoresistance (GMR), and granular or ceramic high-temperature superconducting (HTS) materials. However, in order to improve the important parameters of a magnetic field sensor, in particular, to reduce δB , it is necessary to use concentrators of a measured (external) magnetic field that are called the magnetic flux transformers (MFTs). For this purpose, the property of superconductors to preserve the magnetic flux in a closed circuit without loss is often used.

The MFT elements based on HTS film materials are used in many magnetometers, where MSEs are SQUIDs [5], Hall sensors [6], sensors based on the GMR effect [7], sensors based on the magneto-resistive effect in ceramic HTS materials [8-10], etc.

As was shown in studies [11-13], the efficiency of the MFT can be increased by optimal fragmentation of its active strips into numerous parallel micro-, submicro-, and nanosized branches and slits. In this case, the MFT is separated from the MSE by an insulator film and concentrates an external magnetic field in the direction parallel to the substrate surface. In this work, we present the results of the calculations of the MFTs based on HTS film materials in a magnetic field sensor (MFS). Superconducting film loops serve as the MFT; as the MSE, different magnetoresistive elements can be used.

The MFT and MSE lie in one plane and are separated from one another by gaps; a magnetic field to be measured is concentrated in the direction perpendicular to the substrate surface. We investigate the possibility of improving the important parameters of the MFT by local fragmentation of its active strips into numerous parallel superconducting branches and slits at a technological linewidth resolution of $100 \div 10000$ nm.

2. MATERIALS AND METHODS

The object of the study is the factor F of the effective concentration of a magnetic field on the MSE for the case when the HTS-film-based MFT and the MSE lie in one plane and do not intersect. To increase F , the MFT active strips were split into several parallel branches in the areas adjacent with the MSE. The MFT was calculated with regard to the size effect when the current distribution in superconducting films significantly depends on their width. The following condition is satisfied for all superconducting films: the superconducting film width is much more than λ^2/h , where λ – the London penetration depth of the magnetic field, h – the superconducting film half-thickness.

The MFT comprises two active strips with the MSE symmetrically positioned between them (see Fig. 1a and Fig. 1b).

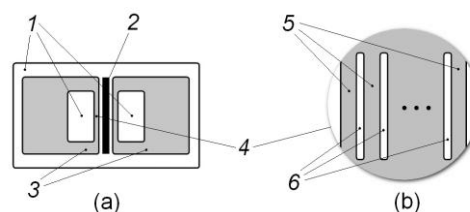


Fig. 1 – Layout of the MFT and MSE: (a) substrate – 1, MSE – 2, and superconducting MFT loops – 3; (b) MFT active strip consisting of numerous branches – 4 (enlarged). The shaded and unshaded areas show superconducting branches – 5, and slits – 6, respectively

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The results obtained can be used for estimating possible enhancement of the efficiency of the weak magnetic field sensor considered in [7], in which a material with the GMR effect was used as the MSE and an HTS Y-Ba-Cu-O film was used as the MFT. In this sensor, the active MFT strip width is 1 μm and, according to the data given in Table 2 (case $\lambda = 250$ nm, $w_p = w_a = 100$ nm), at the optimal splitting of its MFT active strip the gain factor of the sensor will grow by more than 100%. One may expect that the magnetic field resolution δB will correspondingly decrease and the dynamic range of the MFS will broaden.

4. CONCLUSIONS

The analysis of the obtained results shows that fragmentation of the MFT active strips into nanosized superconducting branches and slits (the slit width lies within $\sim 100 - 10000$ nm) makes it possible to increase the MFT gain factor and, correspondingly, the concentration of an external magnetic field on the MSE, by a factor of more than 6 in the case of a wide ($\sim 10 \mu\text{m}$) MSE and by more than 4 in the case of a narrow ($\sim 1 \mu\text{m}$) one.

The value of F_{max} can be further increased by decreasing the gap between the MFT active strips and the MSE or by using the materials with high J_c and low λ , e.g., niobium films as the MFT. Indeed, in niobium heteroepitaxial layers (NHEL) on sapphire substrates (highly textured, nearly single-crystal) at the temperature $T \sim 4\text{K}$ the values $J_c \sim 10^7$ A/cm² and $\lambda \sim 50$ nm are attained [13, 14]. The choice of the NHEL as the MFT will apparently lead to the growth of F_{max} by more than an order of magnitude relative to

the considered here HTS materials with the values $J_c \sim 10^6$ A/cm² and $\lambda \sim 200-250$ nm. The niobium films have already demonstrated their higher efficiency (higher values of F) as compared to the films in the Y-123 system when used as a material for the MFT with continuous active strips [7]. Certainly, the growth of F and F_{max} will ensure the reduction of the magnetic field resolution of the MFS ($\sim 1/F$) [11-12] for detecting weaker magnetic fields.

The structure of MFS considered in this work is planar: the MFT and MSE lie in one plane and do not intersect. Consequently, such a single-layer film sensor of weak magnetic fields is much easier to fabricate as compared to the multilayer structures often used in SQUIDS.

At present, there are no high-temperature superconductors that would allow connecting their ends so that the closed ring had no superconductivity (magnetic flux) loss and could serve as the MFT element. We believe that the magnetic flux transformer based on superconductivity films with the nanostructured active strips will facilitate solving the above-mentioned problem [15].

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REFERENCES

1. D. Robbes, *Sensor. Actuat. A-Phys.* **129**, 86 (2006).
2. I.K. Kominis, T.W. Kornack, J.C. Allred, and M.V. Romalis, *Nature* **422**, 596 (2003).
3. T.H. Sander, J. Preusser, R. Mhaskar, J. Kitching, L. Trahms, S. Knappe, *Biomed. Opt. Express* **3** No5, 981 (2012).
4. J. Deak, A.H. Miklich, J. Slonczewski, R.H. Koch, *Appl. Phys. Lett.* **69** No8, 1157 (1996).
5. J.M. Jaycox, M.B. Ketchen, *IEEE Trans. Magn.* **MAG-17**, 400 (1981).
6. S. Linzen, F. Schmidt, F. Schmidl, *Physica C* **372-376**, 146 (2002).
7. M. Pannetier, C. Fermon, G. Le Goff, *Science* **304** (5677), 1648 (2004).
8. L.P. Ichkitidze, *Patent RU* 2289870.
9. L.P. Ichkitidze, *Physica C* **435**, 140 (2006).
10. L.P. Ichkitidze, *Physica C* **460-462**, 781 (2007).
11. L.P. Ichkitidze, A.N. Mironyuk, *Physica C* **472**, 57 (2012).
12. L.P. Ichkitidze, A.N. Mironyuk, *J. Phys. Conf. Ser.* **400(2)**, 022032 (2012).
13. L.P. Ichkitidze, V.I. Skobelkin, R.A. Bablidze, and V.P. Kuznetsov, *Fizika Nizkih Temperatur (USSR)* **12(5)**, 474 (1986).
14. L.P. Ichkitidze, V.I. Skobelkin, R.A. Bablidze, *Fizika Tverdого Tela (USSR)* **27(10)**, 474 (1986).
15. N.V. Porohov, E.E. Levin, M.L. Chuharkin, *J. Commun. Technol. El.* **57(10)**, 1128 (2012).